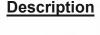




Model H100NA30X4

RF Power

Flange Attenuator 100 Watts, 30 dB



The H100NA30X4 is high performance Aluminum Nitride (AIN) high power flange mount attenuator intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators, and for use in power monitoring. The termination is also RoHS compliant!

General Specifications

Resistive Element	Thick film
Substrate	AIN Ceramic
Cover	Alumina Ceramic
Mounting Flange	Nickel Plated Copper
Operating Temperature	-55 to +150°C (see de rating chart)

Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. **All dimensions in inches.**

Electrical Specifications

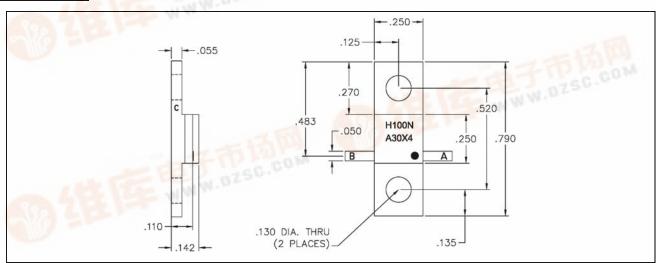
Attenuation Value:	30 dB, +5/-2 dB, DC - 2.2 GHz 30 dB, +7/-2 dB, 2.2 GHz – 2.7 GHz
Power:	100 Watts
Frequency Range:	DC – 2.7 GHz
Return Loss	>24 dB to 2.2 GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. Specifications subject to change.

Features:

- RoHS Compliant
- 100 Watts
- DC 4.0 GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested
- Small Size

Outline Drawing



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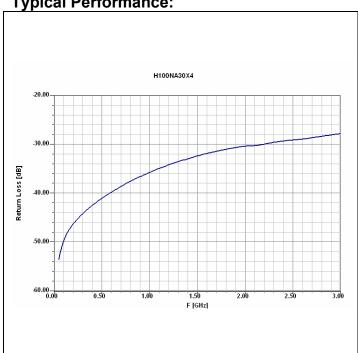
USA/Canada: Toll Free:

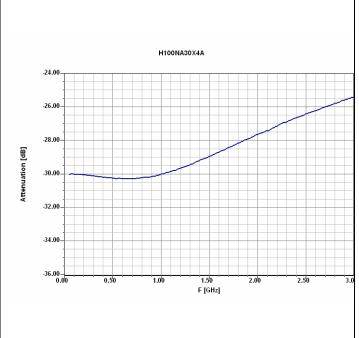
(315) 432-8909 (800) 544-2414





Typical Performance:

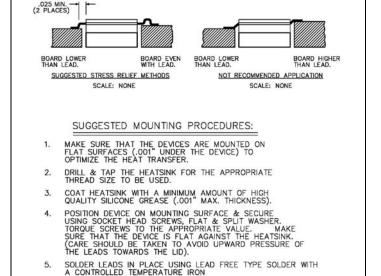




Power De-rating:

POWER DERATING POWER 100 75 -RATED 50 -25 -Ы 0 % 25 50 75 100 125 150 SOLDER INTERFACE TEMPERATURE - "C

Mounting Footprint and Procedure:



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